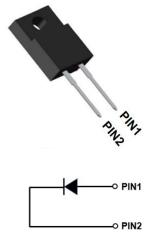
YJD106504FQG3Q

V _{RRM}	650V
I _{F(130°C)}	4A
Q _c	10nC



Features

- Positive temperature coefficient
- Temperature-independent switching
- Maximum working temperature at 175 °C
- Unipolar devices and zero reverse recovery current
- Zero forward recovery current
- Essentially no switching losses
- Reduction of heat sink requirements
- AEC-Q101 qualified
- High-frequency operation
- Reduction of EMI

Typical Applications

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

Mechanical Data

- Package: ITO-220AC Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant, halogen-free
- Terminals: Tin plated leads
- Polarity: As marked

■Maximum Ratings (Tc=25°C Unless otherwise specified)

PARAMTETER	SYMBOL	UNIT	VALUE
Device marking code			D106504FQG3
Reverse voltage (Repetitive peak) @ T _j =25°C	V _{RRM}	V	650
Reverse voltage (Surge peak) @ T _j =25°C	V _{RSM}	V	650
Reverse voltage (DC) @ Tj=25°C	V _{DC}	V	650
Continuous forward current @ $T_c=25^{\circ}C$		A	8
Continuous forward current @ T _c =130°C	I _F		4
Non-repetitive peak forward surge current @ T_c =25°C, tp=10ms, Half Sine Wave	I _{FSM}	А	40
Power Dissipation@ T_c =25°C	5	w	30
Power Dissipation@ T _c =110°C	P _{TOT}		13
i²t Value@ T _c =25°C ,tp=10ms	∫ i²dt	A ² S	8
Operating junction and Storage temperature range	T _j ,T _{stg}	°C	-55 to +175

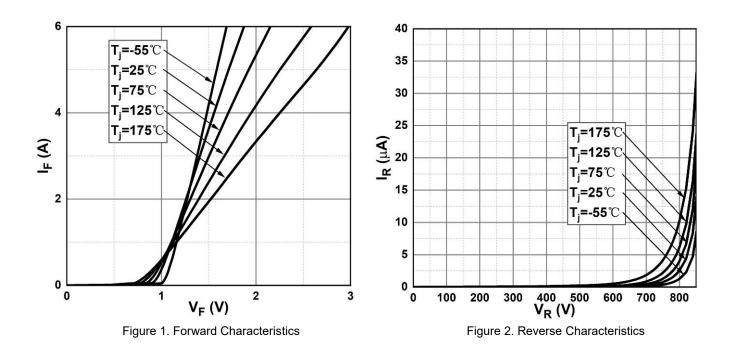
Electrical Characteristics

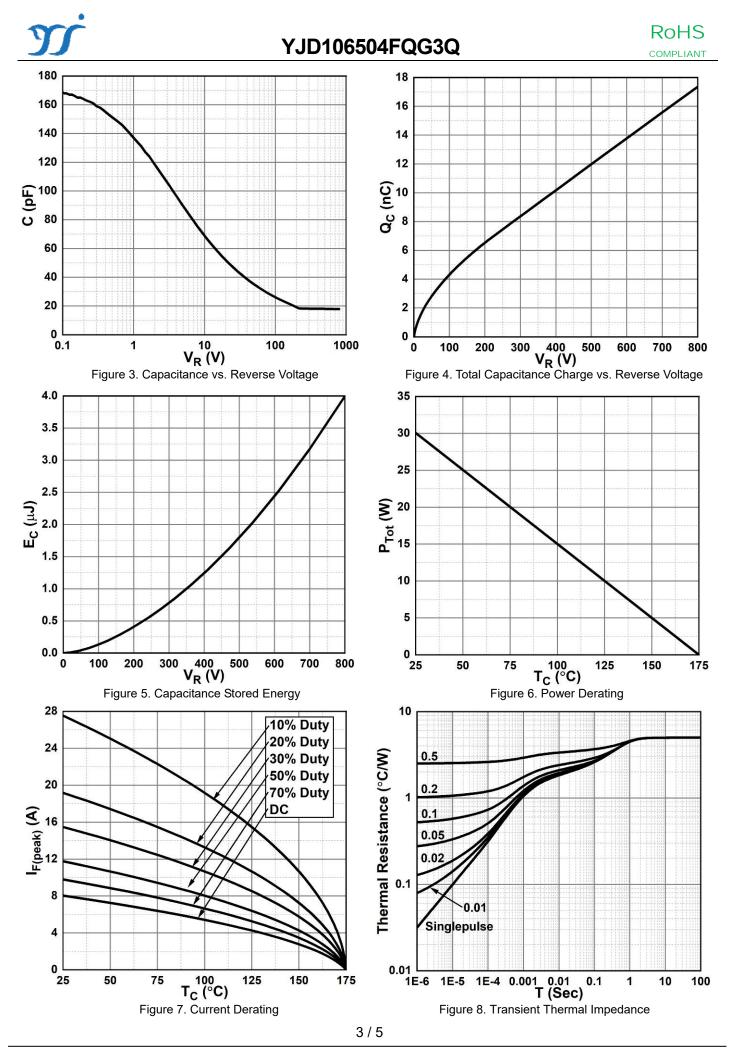
PARAMTETER	SYMBOL	UNIT	TEST CONDITIONS	Тур.	Max.
Forward voltage drop	V _F	V	I _F =4A, T _j =25°C	1.56	1.68
			I _F =4A, T _j =175°C	2.28	-
Reverse leakage current	I _R	μA	V _R =650V, T _j =25°C	0.2	10
			V _R =650V, T _j =175°C	1	-
Total capacitive charge	Q _c	nC	V_R =400V, T _j =25°C , Q_C = \int_0^{VR} C(V)dV	10	-
Total capacitance	С	pF	V _R =0V, f=1MHZ	173	-
			V _R =200V, f=1MHZ	18.3	-
			V _R =400V, f=1MHZ	18.1	-
Capacitance Stored Energy	Ec	μJ	V _R =400V	1.25	-

■Thermal Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Thermal resistance	$R_{_{ ext{ heta}J\text{-}C}}$	°C /W	4.99

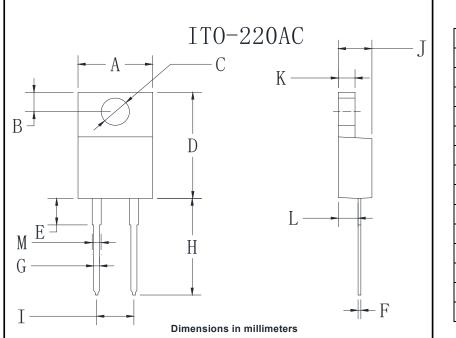
■Typical Characteristics







Outline Dimensions



ITO-220AC				
Dim	Min	Мах		
А	9.8	10.2		
В	2.25	2.75		
С	2.95	3.45		
D	14.75	15.25		
Е	3.5	4.1		
F	0.45	0.75		
G	0.45	0.75		
Н	13.35	14.15		
I	4.97	5.23		
J	4.3	4.8		
К	2.5	2.74		
L	2.58	2.82		
М	1.03	1.43		



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